

■ **FEATURES**

- UL recognition, file #E230084
- Glass passivated chip junction
- Ideal for printed circuit boards
- High surge current capability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

■ **TYPICAL APPLICATIONS**

General purpose use in AC/DC bridge full wave rectification for monitor, TV, printer, power supply, switching mode power supply, adapter, audio equipment, and home appliances applications.

■ **MECHANICAL DATA**

- **Package:** GBU
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked on body

■ **MAXIMUM RATINGS** ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	GBU10005A	GBU1001A	GBU1002A	GBU1004A	GBU1006A	GBU1008A	GBU1010A
Device marking code			GBU10005A	GBU1001A	GBU1002A	GBU1004A	GBU1006A	GBU1008A	GBU1010A
Maximum Repetitive Peak Revers Voltage	VRRM	V	50	100	200	400	600	800	1000
Maximum RMS Voltage	VRMS	V	35	70	140	280	420	560	700
Maximum DC blocking Voltage	VDC	V	50	100	200	400	600	800	1000
Average rectified output current @60Hz sine wave, R-load	IO	A	With heatsink $T_c = 110^\circ\text{C}$						
			Without heatsink $T_a = 25^\circ\text{C}$						
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave, 1 cycle, $T_j = 25^\circ\text{C}$	IFSM	A	10.0						
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, $T_j = 25^\circ\text{C}$			3.6						
Current squared time @1ms $\leq t \leq 8.3$ ms $T_j = 25^\circ\text{C}$, Rating of per diode	I ² t	A ² S	200						
Storage temperature	T _{stg}	°C	400						
Junction temperature	T _j	°C	166						
Dielectric strength @ Terminals to case, AC 1 minute	V _{dis}	KV	-55 ~ +150						
Mounting torque @Recommend torque: 5kg·cm	Tor	kg·cm	-55 ~ +150						
			2.5						
			8						

■ **ELECTRICAL CHARACTERISTICS** ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	GBU10005A	GBU1001A	GBU1002A	GBU1004A	GBU1006A	GBU1008A	GBU1010A
Maximum instantaneous forward voltage drop per diode	V _F	V	I _{FM} =5.0A				1.0			
Maximum DC reverse current at rated DC blocking voltage per diode	I _R	μA	T _j =25°C				5			
			T _j =125°C				100			
Typical junction capacitance	C _j	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C				70			

■ **THERMAL CHARACTERISTICS** ($T_a=25^\circ\text{C}$ Unless otherwise specified)

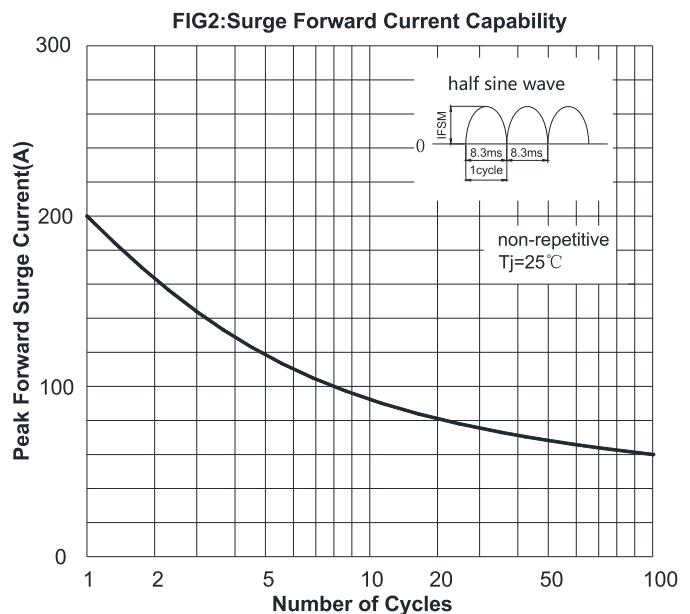
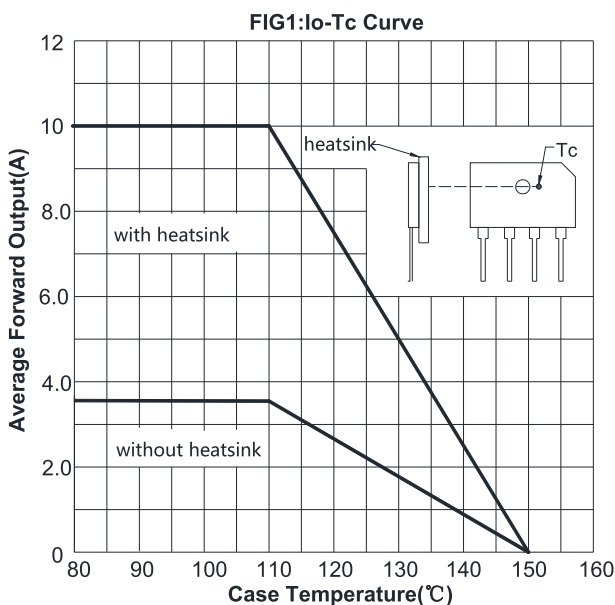
PARAMETER		SYMBOL	UNIT	GBU10005A	GBU1001A	GBU1002A	GBU1004A	GBU1006A	GBU1008A	GBU1010A
Thermal Resistance	Between junction and ambient, Without heatsink	R _{θJ-A}	°C/W				25.0			
	Between junction and case, With heatsink	R _{θJ-C}					2.0			

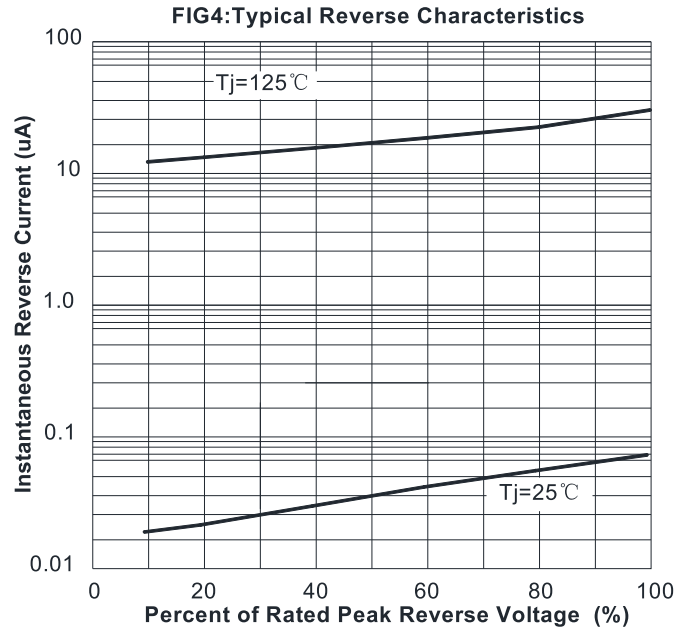
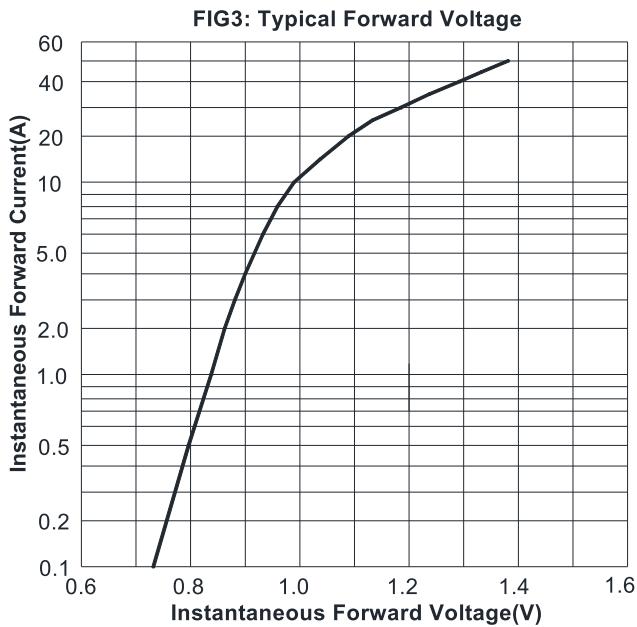
Note: Device mounted on 75mm x 45mm x 5.5mm Aluminum Plate Heatsink.

■ **PACKAGING INFORMATION**

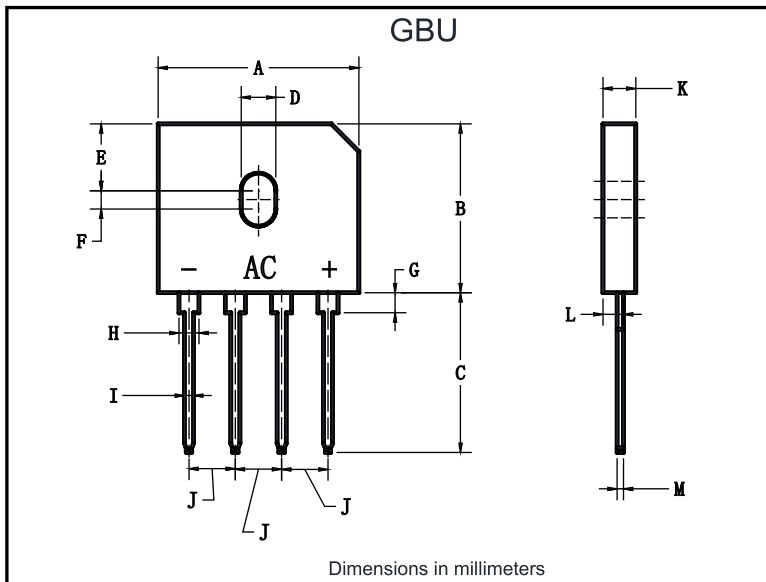
PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
GBU10005A THRU GBU1010A	B1	Approximate 3.96	20	1000	2000	TUBE

■ **CHARACTERISTICS (TYPICAL)**





OUTLINE DIMENSIONS



GBU		
Dim	Min	Max
A	21.80	22.30
B	18.30	18.80
C	17.50	18.00
D	3.50	4.10
E	7.40	7.90
F	1.65	2.16
G	1.91	2.54
H	2.06	2.54
I	1.02	1.27
J	4.83	5.33
K	3.30	3.56
L	2.40	2.66
M	0.46	0.56